

AMENDMENTS TO THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application:

1-18. (Canceled)

19. (Previously presented) An active matrix substrate comprising:

switching elements disposed in a shape of a matrix;

gate signal lines controlling the switching elements;

source signal lines connected to the switching elements and formed orthogonal to the gate signal lines;

an interlayer insulating film formed over at least the switching elements, the gate signal lines, and the source signal lines; and

pixel electrodes formed over at least the interlayer insulating film and in electrical communication with respective switching elements through contact holes defined in the interlayer insulating film,

wherein the pixel electrodes are comprised of a photosensitive conductive material,

wherein the photosensitive conductive material of the pixel electrodes has negative type photosensitivity so that only exposed portions thereof remain, and wherein the gate signals lines and the source signal lines are used as masks during exposure of the negative type photosensitive conductive material of the pixel electrodes from a back side of the substrate so that an array of pixels of the substrate have substantially uniform parasitic capacitance between pixel electrodes and signal lines.

20. (Previously presented) The active matrix substrate as defined in claim 19, wherein the photosensitive conductive material is transparent.

21. (Previously presented) The active matrix substrate as defined in claim 19, wherein the photosensitive conductive material is made from photosensitive resin and conductive particles dispersed in the photosensitive resin.